

SGM829 Microprocessor Supervisory Circuit with Programmable Delay Time

GENERAL DESCRIPTION

The SGM829 family can monitor system voltages from 1.8V to 5V. When the V_{DD} voltage falls below the preset threshold (V_{IT}) or the manual reset (nMR) pin is driven low, the open-drain nRESET output is asserted. After the V_{DD} voltage and nMR voltage return higher than their respective thresholds, the nRESET output remains low within the user-adjustable delay time.

The SGM829 uses a precision reference to achieve 1% threshold accuracy. The fixed reset timeout period can be set to 0.29ms by leaving the SRT pin open. The programmable reset timeout period can be set from 1.25ms to 10s through an external capacitor connected to the SRT pin. Low quiescent current makes the SGM829 very suitable for battery-powered applications.

The SGM829 is available in a Green SOT-23-5 package.

FEATURES

- Adjustable Reset Timeout Period: 1.25ms to 10s
- Low Quiescent Current: 0.6µA (TYP)
- High Threshold Accuracy: 1% (TYP)
- Factory-Set Detection Voltages: 1.8V to 5V
- Manual Reset (nMR) Input
- Open-Drain nRESET Output
- Available in a Green SOT-23-5 Package

APPLICATIONS

Computers Portable Equipment Intelligent Instruments Microprocessor Systems Critical µP Power Monitoring

TYPICAL APPLICATION

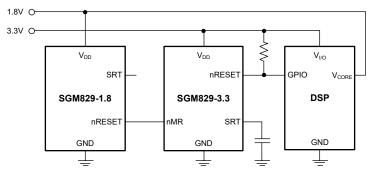


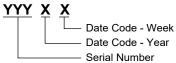
Figure 1. Typical Application Circuit

PACKAGE/ORDERING INFORMATION

MODEL	THRESHOLD VOLTAGE (VIT) (V)	PACKAGE DESCRIPTION	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGM829-1.8	1.67	SOT-23-5	SGM829-1.8XN5G/TR	R70XX	Tape and Reel, 3000
SGM829-1.9	1.77	SOT-23-5	SGM829-1.9XN5G/TR	R72XX	Tape and Reel, 3000
SGM829-2.5	2.33	SOT-23-5	SGM829-2.5XN5G/TR	R75XX	Tape and Reel, 3000
SGM829-2.7	2.52	SOT-23-5	SGM829-2.7XN5G/TR	R77XX	Tape and Reel, 3000
SGM829-2.9	2.7	SOT-23-5	SGM829-2.9XN5G/TR	R79XX	Tape and Reel, 3000
SGM829-3.0	2.79	SOT-23-5	SGM829-3.0XN5G/TR	R3CXX	Tape and Reel, 3000
SGM829-3.3	3.07	SOT-23-5	SGM829-3.3XN5G/TR	R7BXX	Tape and Reel, 3000
SGM829-3.7	3.45	SOT-23-5	SGM829-3.7XN5G/TR	R7DXX	Tape and Reel, 3000
SGM829-4.0	3.73	SOT-23-5	SGM829-4.0XN5G/TR	R7FXX	Tape and Reel, 3000
SGM829-4.5	4.2	SOT-23-5	SGM829-4.5XN5G/TR	R81XX	Tape and Reel, 3000
SGM829-5.0	4.65	SOT-23-5	SGM829-5.0XN5G/TR	R83XX	Tape and Reel, 3000

MARKING INFORMATION

NOTE: XX = Date Code.



Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

Microprocessor Supervisory Circuit with Programmable Delay Time

ABSOLUTE MAXIMUM RATINGS

V _{DD} to GND	-0.3V to 7V
SRT to GND	0.3V to V _{DD} + 0.3V
nRESET, nMR to GND	-0.3V to 7V
nRESET Pin Current	±5mA
Package Thermal Resistance	
SOT-23-5, θ _{JA}	
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (Soldering, 10s)	+260°C
ESD Susceptibility	
НВМ	4000V
CDM	1000V

RECOMMENDED OPERATING CONDITIONS

Input Supply Voltage Range, V _{DD}	1.65V to 6.5V
SRT Pin Voltage, V _{SRT}	V _{DD} (MAX)
nMR Pin Voltage, V _{nMR}	0V to 6.5V
nRESET Pin Voltage, V _{nRESET}	0V to 6.5V
nRESET Pin Current, InRESET	0.0003mA to 5mA
Operating Junction Temperature Range	40°C to +125°C

OVERSTRESS CAUTION

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

ESD SENSITIVITY CAUTION

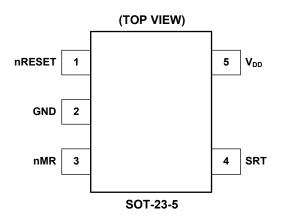
This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.



PIN CONFIGURATION



PIN DESCRIPTION

PIN	NAME	I/O	FUNCTION
1	nRESET	0	Active-Low Reset Output Pin. nRESET remains low if the V _{DD} input is below V _{IT} or nMR is logic low. It goes (or remains) low for the reset timeout period after the V _{DD} voltage exceeds V _{IT} and nMR pin is driven high. It is recommended to connect a 10k Ω to 1M Ω pull-up resistor to this pin which enables the reset voltages greater than V _{DD} .
2	GND	_	Ground.
3	nMR	I	Manual Reset Input Pin. Pulling this pin (nMR) low will assert nRESET. nMR is internally pulled up to V_{DD} by a 100k Ω resistor.
4	SRT	I	Set Reset Timeout Input. Connect a capacitor between SRT and ground to set the timeout period. The pin can be left open, but it cannot be connected to V _{DD} . Determine the period as follows: $T_D (\mu s) = (2.8 \times 10^6) \times C_{SRT} (\mu F) + 290\mu s.$
5	V_{DD}	I	Supply Voltage. It is recommended to place a 0.1µF ceramic capacitor close to this pin.

NOTE: I: input, O: output.



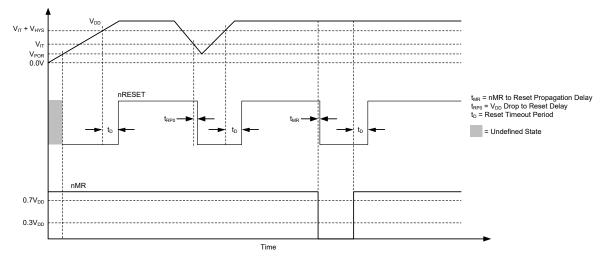
ELECTRICAL CHARACTERISTICS

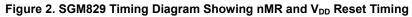
 $(V_{DD} = 1.65V \text{ to } 6.5V, R_{LRESET} = 100 \text{k}\Omega^{(1)}, T_{J} = -40^{\circ}\text{C}$ to +85°C, typical values are at $T_{J} = +25^{\circ}\text{C}$, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
Input Supply Voltage Range	V _{DD}		1.65		6.5	V	
Supply Current (Current into V _{DD} Pin)		V _{DD} = 3.3V, nRESET not asserted, nMR, nRESET, SRT open 0.6		0.6	1.5	μA	
	I _{DD}	V _{DD} = 6.5V, nRESET not asserted, nMR, nRESET, SRT open		0.9	2	μ	
	V	$1.3V \le V_{DD} < 1.8V, I_{OL} = 0.4mA$			0.2		
Low-Level Output Voltage	V _{OL}	V_{OL} 1.8V $\leq V_{DD} \leq 6.5V, I_{OL} = 1mA$			0.3	V	
Power-On Reset Voltage	V _{POR}	$V_{OL_{MAX}} = 0.2V$, $I_{nRESET} = 15\mu A$			0.8	V	
		T _J = +25°C	-1.0		1.0	0/	
Negative-Going Input Threshold Accuracy	V _{IT}	$T_J = -40^{\circ}C$ to $+85^{\circ}C$	-1.3		1.3	%	
Hysteresis on V _{IT} ⁽²⁾	steresis on V _{IT} ⁽²⁾ V _{HYS}			$50 \times V_{IT}$		mV	
V _{DD} Drop to Reset Delay	t _{RP0}	Drop = V_{IT} - 250mV, T _J = -40°C to +85°C		85		μs	
nMR Internal Pull-Up Resistance	R_{nMR}	$T_J = -40^{\circ}C$ to $+85^{\circ}C$		100		kΩ	
-MD lesses	VIH	Logic high	$0.7 \times V_{DD}$			V	
nMR Input	VIL	Logic low			$0.3 \times V_{DD}$	v	
Input Capacitance, Any Pin	C _{IN}	SRT pin, $V_{IN} = 0V$ to V_{DD} , T _J = -40°C to +85°C		5		pF	
Input Capacitance, Any Fin	Cin	Other pins, $V_{IN} = 0V$ to 6.5V, T _J = -40°C to +85°C		5		μr	
nMR Glitch Rejection		$T_J = -40^{\circ}C$ to $+85^{\circ}C$		100		ns	
nMR to Reset Propagation Delay	t _{nMR}	$T_J = -40^{\circ}C$ to $+85^{\circ}C$		240		ns	
Peact Timesut Davied		SRT open	0.15	0.29	0.40		
Reset Timeout Period	t _D	C _{SRT} = 1nF	1.5	2.8	4.0	ms	
SRT Source Current		$T_J = -40^{\circ}C$ to $+85^{\circ}C$		430		nA	
SRT Source Threshold Voltage	$V_{\text{TH-RAMP}}$	$T_J = -40^{\circ}C$ to $+85^{\circ}C$		1.205		V	

NOTES:

- 1. R_{LRESET} is the resistor connected to the nRESET pin.
- 2. Guaranteed by design and not tested in production.

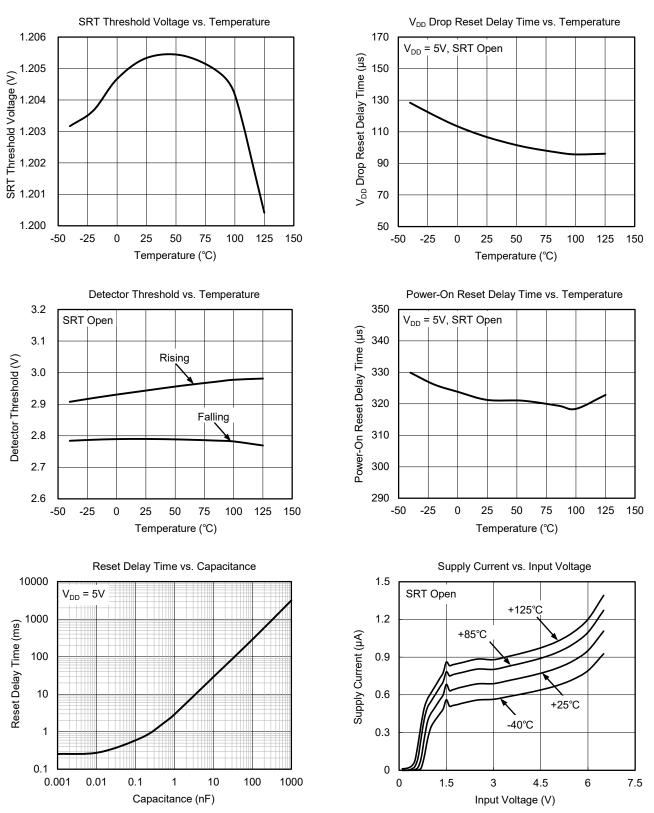




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TYPICAL PERFORMANCE CHARACTERISTICS

Test for SGM829-3.0 only, T_J = +25°C, unless otherwise noted.



FUNCTIONAL BLOCK DIAGRAM

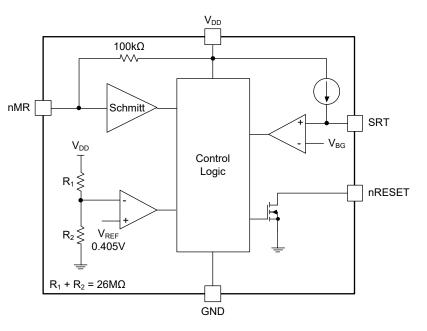


Figure 3. Block Diagram



DETAILED DESCRIPTION

When the V_{DD} voltage falls below V_{IT} or the nMR pin is driven low, the open-drain nRESET output is asserted. After the V_{DD} and nMR voltages exceed their respective thresholds, the nRESET output remains low within the user-adjustable delay time.

Feature Description

The SGM829 device has a reset delay time adjustment function and a wide range of detection thresholds, so it can be widely used in various applications. The detection threshold voltages are factory-set from 1.8V to 5V. The reset timeout period can be set from 1.25ms to 10s through programming an external capacitor which is connected to the SRT pin.

Selecting the Reset Delay Time

When the V_{DD} voltage exceeds the V_{DD} threshold voltage, a current source will start to charge the SRT capacitor and the SRT voltage will rise. When the SRT voltage exceeds 1.205V, the nRESET voltage will change from low to high.

Therefore, there is a delay time between the point of V_{DD} reaching its threshold voltage and the nRESET active-high point. The delay time can be calculated according to the following equation:

 $T_D(\mu s) = (2.8 \times 10^6) \times C_{SRT}(\mu F) + 290\mu s$ (1)

Manual Reset (nMR) Input

The manual reset (nMR) input allows the operator, test technician, or external logic circuit to initiate a reset. A logic low ($0.3 \times V_{DD}$) on nMR forces the nRESET low. After nMR returns to a logic high and the V_{DD} voltage rises above its reset threshold, nRESET is deasserted after a reset delay time period (t_D). nMR is pulled up to V_{DD} with an internal 100k Ω resistor. This pin can be left floating if nMR is not used.

Figure 4 shows how to use nMR to monitor multiple system voltages. If the logic signal does not drive nMR fully to V_{DD} , some extra current will flow into V_{DD} due to the pull-up resistor on nMR. Figure 5 shows how to use an external FET to minimize the current draw.

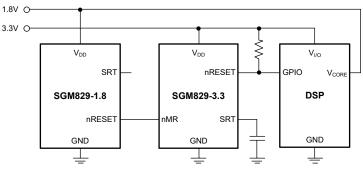


Figure 4. Monitor Multiple System Voltages Using the nMR Pin

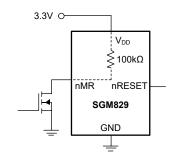


Figure 5. An External MOSFET is used to Minimize IDD



SGM829

DETAILED DESCRIPTION (continued)

nRESET Output

As long as V_{DD} voltage exceeds V_{IT} and the nMR is logic high, nRESET remains high (deasserted). Either V_{DD} is lower than V_{IT} or nMR is set low, nRESET will be low (asserted).

If nMR returns to logic high again and V_{DD} voltage exceeds $V_{IT} + V_{HYS}$, nRESET will remain low for a fixed reset delay time due to the delay circuit function. As soon as the reset delay has expired, the nRESET turns into logic high. The pull-up resistor between nRESET and V_{DD} can be used to reset the microprocessor signal to obtain a voltage above V_{DD} voltage. The pull-up resistor should be no less than 10k Ω due to the limited nRESET pull-down ability.

Device Functional Modes

Table 1. Matrices of the nRESET Output

nMR	$V_{DD} > V_{IT}$	nRESET
L	0	L
L	1	L
Н	0	L
Н	1	Н

Normal Operation (V_{DD} > V_{DD_MIN})

When the V_{DD} voltage is higher than V_{DD_MIN} , the logic state of nRESET is determined by V_{DD} and the logic state of nMR.

• nMR high: When V_{DD} voltage is higher than 1.65V for a selected time (t_D), the nRESET logic state corresponds to V_{DD} relative to V_{IT} .

- nMR low: nRESET is held low regardless of V_{DD} voltage in this mode.

Above Power-On Reset but Lower than VDD_MIN

$(V_{POR} < V_{DD} < V_{DD_{MIN}})$

When the V_{DD} voltage is lower than V_{DD_MIN} and higher than the power-on reset voltage (V_{POR}), the nRESET is asserted and driven to a low-impedance state.

Below Power-On Reset (V_{DD} < V_{POR})

When the V_{DD} voltage is lower than the required voltage (V_{POR}), the nRESET voltage is undefined. In the case of nRESET pulling up to V_{DD} through a 100k Ω resistor, nRESET voltage is equal to or lower than V_{DD} voltage.



APPLICATION INFORMATION

The SGM829 requires a voltage supply within 1.65V and 6.5V. Figure 6 shows a typical application of the SGM829-2.5 used with a 2.5V microprocessor. Normally, the nRESET output is connected to the nRESET input of the microprocessor. It is necessary to connect a 1M Ω pull-up resistor between nRESET and V_{DD} to keep the nRESET logic high if it is not asserted.

The reset delay time can be set by SRT while it depends on the requirement of microprocessor. If left it open, a typical 20ms of reset delay time is set.

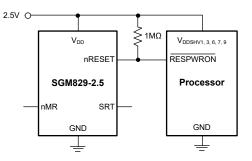


Figure 6. SGM829 Typical Application circuit with a Microprocessor

Layout Guidelines

It is recommended to connect a 0.1μ F ceramic capacitor to the V_{DD} pin as close as possible. If there is no connection capacitor, minimize the parasitic capacitor to avoid a significant impact on the nRESET delay time.

REVISION HISTORY

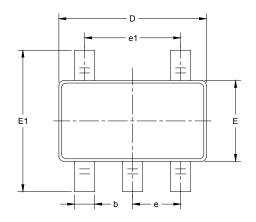
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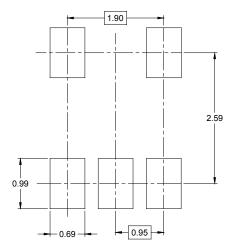
AUGUST 2022 – REV.A to REV.A.1	Page					
Updated General Description section						
Jpdated Detail Description section						
Changes from Original (MAY 2021) to REV.A	Pag					



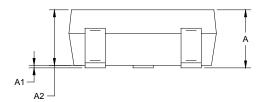
PACKAGE OUTLINE DIMENSIONS

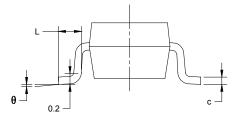
SOT-23-5





RECOMMENDED LAND PATTERN (Unit: mm)





Symbol	-	nsions meters	Dimensions In Inches		
	MIN	MAX	MIN	MAX	
A	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E	1.500	1.700	0.059	0.067	
E1	2.650	2.950	0.104	0.116	
е	0.950	BSC	0.037	BSC	
e1	1.900 BSC		0.075	BSC	
L	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	

TAPE AND REEL INFORMATION

REEL DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SOT-23-5	7″	9.5	3.20	3.20	1.40	4.0	4.0	2.0	8.0	Q3

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton	
7" (Option)	368	227	224	8	
7"	442	410	224	18	00002

